

Features

■ TP182A1/A2 VOLTAGE OFFSET: ±50uV (MAX)

■ TP182A3/A4 VOLTAGE OFFSET: ±35uV (MAX)

■ WIDE COMMON MODE VOLTAGE: -0.3V to +36V

■ SUPPLY VOLTAGE: 2.7V to +30V

■ ACCURACY and ZERO-DRIFT PERFORMANCE

♦ ±1% Gain Error (Max over temperature)

♦ 0.5µV/°C Offset Drift (Max)

◆ 10ppm/°C Gain Drift (Max)

■ THREE GAIN OPTIONS for VOLTAGE OUTPUT

◆ TP182A1: 50V/V◆ TP182A2: 100V/V

◆ TP182A3: 200V/V

◆ TP182A4: 500V/V

■ LOW SUPPLY CURRENT: 120uA (TYP)

■ Rail-to-Rail Output

■ PACKAGE: SC70-6

■ Industrial –40°C to 125°C Operation Range

ESD Rating: Robust 2KV – HBM, 2KV – CDM

■ Higher performance Drop-In Compatible With INA213, INA214, INA199, NCS199 Products

Applications

■ CURRENT SENSING (High-Side/Low-Side)

■ BATTERY CHARGERS

■ POWER MANAGEMENT

■ CELL PHONE CHARGER

■ ELECTRICAL CIGIRATE

■ WIRELESS CHARGER

■ TELECOM EQUIPMENT

Description

The TP182 series of zero-drift, bi-directional current sense amplifier can sense voltage drops across shunts at common-mode voltages from -0.3V to 36V, independent of the supply voltage. Three fixed gains are available: 50V/V, 100V/V and 200V/V. The low offset of the zero-drift architecture enables current sensing with maximum drops across the shunt as low as **10mV** full-scale.

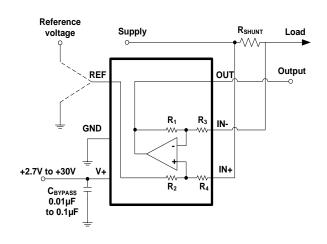
TP182 devices operate from a single +2.7V to 30V power supply, with drawing a typical of 120uA of supply current. All versions are specified from –40°C +125°C, and offered in SC70-6 packages.

GAIN OPTIONS TABLE

PRODUCT	GAIN	R3 and R4	R1 and R2
TP182A1	50	20kΩ	1ΜΩ
TP182A2	100	10kΩ	1ΜΩ
TP182A3	200	5kΩ	1ΜΩ
TP182A4	500	2kΩ	1ΜΩ

$$V_{OUT} = (I_{LOAD} \times R_{SHUNT})GAIN + V_{REF}$$

Application schematic



Pin Configuration

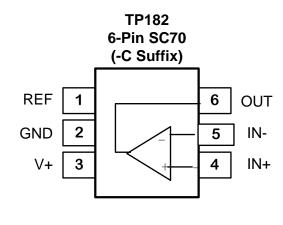




Table of Contents

Features	
Applications	1
Description	
Application schematic	1
Pin Configuration	
Revision History	2
Order Information	3
ESD, Electrostatic Discharge Protection	3
Thermal Resistance	3
Typical Performance Characteristics	
Pin Functions	
Operation Overview	7
Applications Information	
Application schematic	
Selecting RSHUNT	ε
REF Input Impedance Effects	ε
Power Supply Recommendation	8
Proper Board Layout	
Tape and Reel Information	
Package Outline Dimensions	
IMPORTANT NOTICE AND DISCI AIMER	

Revision History

Date	Revision	Notes
2018-11-1	Rev.A.0	Release Version, TP182A1, G=50
2019-4-10	Rev.A.1	Add TP182A2, G=100
2019-7-17	Rev.A.2	Add TP182A3, G=200
2020-09-16	Rev.A.3	Add TP182A4, G=500; update Maximum Working Junction Temperature 150°C
2021-01-21	Rev.A.4	Product HBM ESD is 2kV, Modify "ESD Rating: Robust 2KV - HBM" in Features
		description
2023-08-24	Rev.A.5	The following updates are all about the new datasheet formats or typo, the actual
		product remains unchanged.
		Updated to new format of package dimensions.
		Added tape and reel information.



Order Information

Model Name	Order Number	Gain	Package	Transport Media, Quantity	Package Marking
	TP182A1-CR	50V/V	6-Pin SC70	Tape and Reel, 3,000	9A1
TP182	TP182A2-CR	100V/V	6-Pin SC70	Tape and Reel, 3,000	9A2
17 102	TP182A3-CR	200V/V	6-Pin SC70	Tape and Reel, 3,000	9A3
	TP182A4-CR	500V/V	6-Pin SC70	Tape and Reel, 3,000	9A4

Absolute Maximum Ratings Note 1

Supply Voltage Note 2	42.0V	Current at Supply Pins	±60mA
Input Voltage	GND- 0.3 to 42V	Operating Temperature Range40)°C to 125°C
Input Current: +IN, -IN Note 3	±5mA	Maximum Working Junction Temperatu	ıre150°C
Output Current: OUT	±35mA	Storage Temperature Range –65	5°C to 150°C
		Lead Temperature (Soldering, 10 sec)	260°C

Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

Note 2: The op amp supplies must be established simultaneously, with, or before, the application of any input signals.

Note 3: The inputs are protected by ESD protection diodes to each power supply. If the input extends more than 500mV beyond the power supply, the input current should be limited to less than 10mA.

ESD, Electrostatic Discharge Protection

Symbol	Parameter	Condition	Minimum Level	Unit
НВМ	Human Body Model ESD	ANSI/ESDA/JEDEC JS-001	±2	kV
CDM	Charged Device Model ESD	ANSI/ESDA/JEDEC JS-002	±2	kV

Thermal Resistance

Package Type	θ _{JA}	θ _{JC}	Unit
6-Pin SC70	227	80	°C/W

www.3peak.com 3/ 13 Rev.A.5



Electrical Characteristics

The specifications are at TA = 25°C, VSENSE = VIN+ - VIN-, VS = 5 V, VIN+ = 12V, and VREF = VS / 2, unless otherwise noted

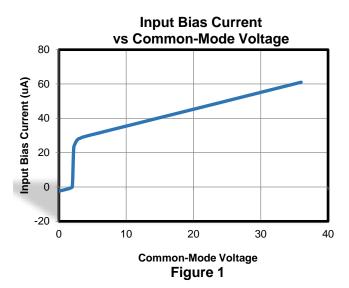
NPUT Vos Input Offset Voltage	Symbol	Parameter	Conditions	Min	Тур	Max	Unit			
VSENSE=0mV, VINY=5V, TP182A3 & TP182A4	INPUT									
V _{CS} TC Input Offiset Voltage Drift VSENSE = 0 mV, 40°C to 126°C 0.1 0.5 μV/°C V _{CS} Common-mode Input Range	Vos	Input Offset Voltage	VSENSE=0mV, VIN+=5V, TP182A1& TP182A2		±10	±50	uV			
Common-mode Input Range			VSENSE=0mV, VIN+=5V, TP182A3 & TP182A4		±10	±35	uV			
CMRR Common Mode Rejection Ratio VIN+ = 5-26 V, VSENSE = 0 mV, 40°C to 125°C 95 120 dB	V _{os} TC	Input Offset Voltage Drift	VSENSE = 0 mV, -40°C to 125°C		0.1	0.5	μV/°C			
In	V _{CM}	Common-mode Input Range	-40°C to 125°C	-0.3		36	V			
Input Offset Current VSENSE = 0 mV 0.4 uA	CMRR	Common Mode Rejection Ratio	VIN+ = 5~26 V, VSENSE = 0 mV, -40°C to 125°C	95	120		dB			
PSRR Power Supply Rejection Ratio Vs = +2.7-18V, VIN+ = +18V, VSENSE = 0 mV ±1 uV/V NOISE RTI **voic*	l _Β	Input Bias Current	VSENSE = 0 mV		35		uA			
NOISE RTI Noise Noise Noise Noise Density	I _{os}	Input Offset Current	VSENSE = 0 mV		0.4		uA			
en Input Voltage Noise Density f = 1kHz 30 nV/NHz OUTPUT FP 182A1 50 V/V TP 182A2 100 V/V TP 182A3 200 V/V TP 182A4 500 V/V GE TC Gain Error VSENSE = -5~5mV, -40°C to 125°C ±0.1% ±1% GETC Gain Error Vs Temperature -40°C to 125°C 3 10 ppm C _{LOAD} Maxim capacitive load No oscillation 1 nF V _{OH} Output Swing from Supply Rail R _{LOAD} = 10kΩ to GND, -40°C to 125°C 0.02 0.05 V V _{OH} Output Swing from GND R _{LOAD} = 10kΩ to GND, -40°C to 125°C 0.01 0.05 V FREQUENCY RESPONSE CLOAD = 10pF, TP182A1 48 kHz CLOAD = 10pF, TP182A2 30 kHz CLOAD = 10pF, TP182A3 20 kHz CLOAD = 10pF, TP182A4 9 kHz	PSRR	Power Supply Rejection Ratio	Vs = +2.7~18V, VIN+ = +18V, VSENSE = 0 mV		±1		uV/V			
OUTPUT G again TP182A1 50 V/V TP182A2 100 V/V TP182A3 200 V/V TP182A4 500 V/V GE Gain Error VSENSE = -5-5mV, -40°C to 125°C ±0.1% ±1% GE TC Gain Error Vs Temperature -40°C to 125°C 3 10 ppm CLOAD Maxim capacitive load No oscillation 1 nF Vo. Output Swing from Supply Rail RLOAD = 10kΩ to GND, -40°C to 125°C 0.02 0.05 V Vo. Output Swing from GND RLOAD = 10kΩ to GND, -40°C to 125°C 0.01 0.05 V FREQUENCY RESPONSE CLOAD = 10pF, TP182A1 48 kHz CLOAD = 10pF, TP182A2 30 kHz CLOAD = 10pF, TP182A3 20 kHz SR Slew Rate 0.6 V/µs POWER SUPPLY V Supply Voltage 2.7 30 V I _Q Quiescent Current VSENSE = 0 mV 120 150 µA TEMPERATURE RANGE -40	NOISE RTI No	te 4								
G ain TP182A1 50 V/V TP182A2 100 V/V TP182A3 200 V/V TP182A4 500 V/V GE Gain Error VSENSE = -5~5mV, -40°C to 125°C ±0.1% ±1% GE TC Gain Error Vs Temperature -40°C to 125°C 3 10 ppm CLOAD Maxim capacitive load No oscillation 1 nF VOI Output Swing from Supply Rail R _{CLOAD} = 10kΩ to GND, -40°C to 125°C 0.02 0.05 V FREQUENCY RESPONSE BW Bandwidth CLOAD = 10pF, TP182A1 48 kHz CLOAD = 10pF, TP182A2 30 kHz CLOAD = 10pF, TP182A3 20 kHz SR Slew Rate 0.6 V/µs POWER SUPPLY V+ Supply Voltage 2.7 30 V I _Q Quiescent Current VSENSE = 0 mV 120 150 µA TEMPERATURE RANGE -40 125 °C	e _n	Input Voltage Noise Density	f = 1kHz		30		nV/√Hz			
G ain TP182A2 100 V/V TP182A3 200 V/V TP182A4 500 V/V GE TC Gain Error VSENSE = -5~5mV, -40°C to 125°C ±0.1% ±1% CLOAD Maxim capacitive load No oscillation 1 nF VOH Output Swing from Supply Rail R _{LOAD} = 10kΩ to GND, -40°C to 125°C 0.02 0.05 V FREQUENCY RESPONSE CLOAD = 10pF, TP182A1 48 kHz BW Bandwidth CLOAD = 10pF, TP182A2 30 kHz CLOAD = 10pF, TP182A3 20 kHz CLOAD = 10pF, TP182A4 9 kHz POWER SUPPLY V+ Supply Voltage 2.7 30 V Io Quiescent Current VSENSE = 0 mV 120 150 μA TEMPERATURE RANGE Specified range -40 125 °C	OUTPUT									
TP182A3			TP182A1		50		V/V			
TP182A3	•	Gain	TP182A2		100		V/V			
GE Gain Error VSENSE = -5~5mV, -40°C to 125°C ±0.1% ±1% GE TC Gain Error Vs Temperature -40°C to 125°C 3 10 ppm C _{LOAD} Maxim capacitive load No oscillation 1 nF V _{OH} Output Swing from Supply Rail R _{LOAD} = 10kΩ to GND, -40°C to 125°C 0.02 0.05 V FREQUENCY RESPONSE CLOAD = 10pF, TP182A1 48 kHz BW Bandwidth CLOAD = 10pF, TP182A2 30 kHz CLOAD = 10pF, TP182A3 20 kHz SR Slew Rate 0.6 V/µs POWER SUPPLY V Supply Voltage 2.7 30 V I ₀ Quiescent Current VSENSE = 0 mV 120 150 µA TEMPERATURE RANGE Specified range -40 125 °C	G		TP182A3		200		V/V			
GE TC Gain Error Vs Temperature -40°C to 125°C 3 10 ppm C _{LOAD} Maxim capacitive load No oscillation 1 nF V _{OH} Output Swing from Supply Rail R _{LOAD} = 10kΩ to GND, -40°C to 125°C 0.02 0.05 V FREQUENCY RESPONSE CLOAD = 10pF, TP182A1 48 kHz CLOAD = 10pF, TP182A2 30 kHz CLOAD = 10pF, TP182A3 20 kHz CLOAD = 10pF, TP182A4 9 kHz POWER SUPPLY V Supply Voltage 2.7 30 V I _Q Quiescent Current VSENSE = 0 mV 120 150 μA TEMPERATURE RANGE -40 125 °C			TP182A4		500		V/V			
C _{LOAD} Maxim capacitive load No oscillation 1 nF V _{OH} Output Swing from Supply Rail R _{LOAD} = 10kΩ to GND, -40°C to 125°C 0.02 0.05 V V _{OL} Output Swing from GND R _{LOAD} = 10kΩ to GND, -40°C to 125°C 0.01 0.05 V FREQUENCY RESPONSE CLOAD = 10pF, TP182A1 48 kHz CLOAD = 10pF, TP182A2 30 kHz CLOAD = 10pF, TP182A2 30 kHz SR Slew Rate 0.6 V/μs POWER SUPPLY V+ Supply Voltage 2.7 30 V Iq Quiescent Current VSENSE = 0 mV 120 150 μA TEMPERATURE RANGE Specified range -40 125 °C	GE	Gain Error	VSENSE = -5~5mV, -40°C to 125°C		±0.1%	±1%				
V _{OH} Output Swing from Supply Rail R _{LOAD} = 10kΩ to GND, -40°C to 125°C 0.02 0.05 V FREQUENCY RESPONSE BW Bandwidth CLOAD = 10pF, TP182A1 48 kHz CLOAD = 10pF, TP182A2 30 kHz CLOAD = 10pF, TP182A3 20 kHz CLOAD = 10pF, TP182A4 9 kHz SR Slew Rate 0.6 V/μs POWER SUPPLY V+ Supply Voltage 2.7 30 V Iq Quiescent Current VSENSE = 0 mV 120 150 μA TEMPERATURE RANGE Specified range -40 125 °C	GE TC	Gain Error Vs Temperature	-40°C to 125°C		3	10	ppm			
Vol. Output Swing from GND R _{LOAD} = 10kΩ to GND, -40°C to 125°C 0.01 0.05 V FREQUENCY RESPONSE BW Bandwidth CLOAD = 10pF, TP182A1 48 kHz CLOAD = 10pF, TP182A2 30 kHz CLOAD = 10pF, TP182A3 20 kHz CLOAD = 10pF, TP182A4 9 kHz POWER SUPPLY V+ Supply Voltage 2.7 30 V Iq Quiescent Current VSENSE = 0 mV 120 150 μA TEMPERATURE RANGE Specified range -40 125 °C	C _{LOAD}	Maxim capacitive load	No oscillation		1		nF			
FREQUENCY RESPONSE BW Bandwidth CLOAD = 10pF, TP182A1 48 kHz CLOAD = 10pF, TP182A2 30 kHz CLOAD = 10pF, TP182A3 20 kHz CLOAD = 10pF, TP182A4 9 kHz SR Slew Rate 0.6 V/μs POWER SUPPLY V+ Supply Voltage 2.7 30 V IQ Quiescent Current VSENSE = 0 mV 120 150 μA TEMPERATURE RANGE Specified range -40 125 °C	V_{OH}	Output Swing from Supply Rail	R_{LOAD} = 10kΩ to GND, -40°C to 125°C		0.02	0.05	V			
BW Bandwidth	V_{OL}	Output Swing from GND	R_{LOAD} = 10kΩ to GND, -40°C to 125°C		0.01	0.05	V			
BW Bandwidth	FREQUENCY	RESPONSE								
BW Bandwidth CLOAD = 10pF, TP182A3 20 kHz CLOAD = 10pF, TP182A4 9 kHz SPECIFIED RANGE CLOAD = 10pF, TP182A4 9 kHz VHZ Slew Rate 0.6 V/μs POWER SUPPLY V+ Supply Voltage 2.7 30 V Iq Quiescent Current VSENSE = 0 mV 120 150 μA TEMPERATURE RANGE Specified range -40 125 °C			CLOAD = 10pF, TP182A1		48		kHz			
CLOAD = 10pF, TP182A3 20 kHz CLOAD = 10pF, TP182A4 9 kHz SR Slew Rate 0.6 V/μs POWER SUPPLY V+ Supply Voltage 2.7 30 V I _Q Quiescent Current VSENSE = 0 mV 120 150 μA TEMPERATURE RANGE Specified range -40 125 °C	DW	Donado si dibi	CLOAD = 10pF, TP182A2		30		kHz			
SR Slew Rate 0.6 V/μs POWER SUPPLY V+ Supply Voltage 2.7 30 V I _Q Quiescent Current VSENSE = 0 mV 120 150 μA TEMPERATURE RANGE Specified range -40 125 °C	BVV	Bandwidth	CLOAD = 10pF, TP182A3		20		kHz			
POWER SUPPLY V+ Supply Voltage 2.7 30 V I _Q Quiescent Current VSENSE = 0 mV 120 150 μA TEMPERATURE RANGE Specified range -40 125 °C			CLOAD = 10pF, TP182A4		9		kHz			
V+ Supply Voltage 2.7 30 V I _Q Quiescent Current VSENSE = 0 mV 120 150 μA TEMPERATURE RANGE Specified range -40 125 °C	SR	Slew Rate			0.6		V/µs			
I _Q Quiescent Current VSENSE = 0 mV 120 150 μA TEMPERATURE RANGE Specified range -40 125 °C	POWER SUP	POWER SUPPLY								
TEMPERATURE RANGE Specified range -40 125 °C	V+	Supply Voltage		2.7		30	V			
Specified range -40 125 °C	ΙQ	Quiescent Current	VSENSE = 0 mV		120	150	μА			
	TEMPERATU	TEMPERATURE RANGE								
Operating range -55 150 °C		Specified range		-40		125	°C			
		Operating range		-55		150	°C			

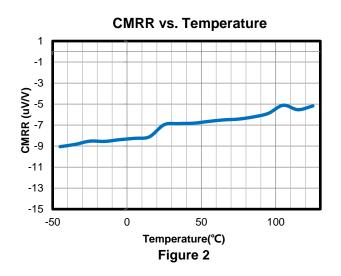
Note 4: RTI = referred to input

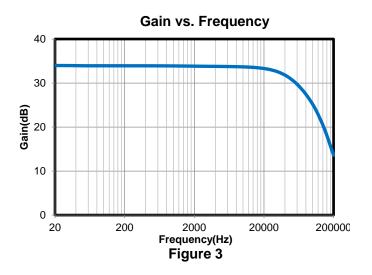


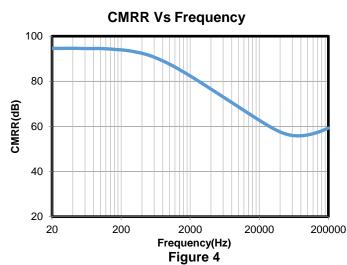
Typical Performance Characteristics

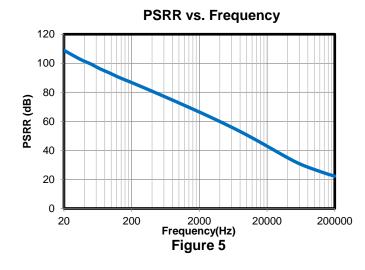
The TP182A1 is used for characteristics at TA = 25°C, VS = 5V, VIN+ =12V, and VREF=VS/2, unless otherwise noted

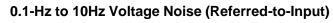


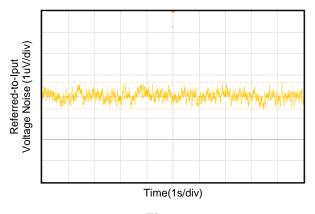












Fiaure 6



Typical Performance Characteristics

The TP182A1 is used for characteristics at TA = 25°C, VS = 5V, VIN+ =12V, and VREF=VS/2, unless otherwise noted

Step response (10-mVpp Input Step)

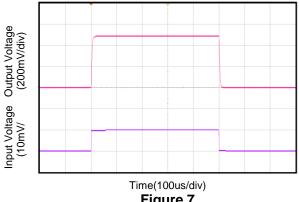
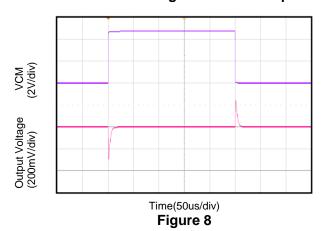


Figure 7

Common-Mode Voltage Transient Response



Noninverting Differential Input Overload

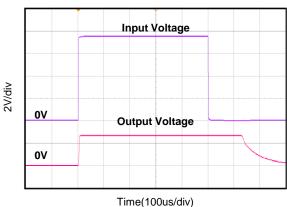
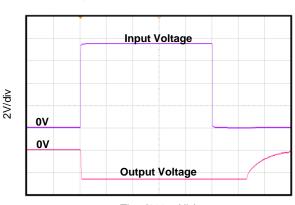


Figure 9

Inverting Differential Input Overload



Time(100us/div) Figure 10

Start-up Response

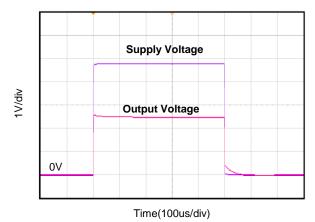


Figure 11

Brownout Recovery

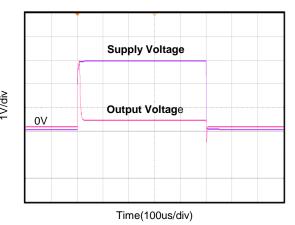
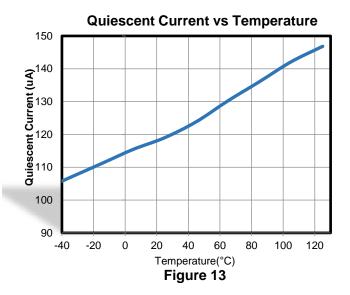


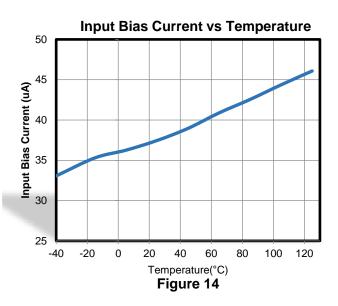
Figure 12



Typical Performance Characteristics

The TP182A1 is used for characteristics at TA = 25°C, VS = 5V, VIN+ =12V, and VREF=VS/2, unless otherwise noted





Pin Functions

IN-: Inverting Input of the Amplifier.

IN+: Non-Inverting Input of Amplifier.

OUT: Amplifier Output. The voltage range extends to within mV

of each supply rail.

REF: Reference voltage

V+: Positive Power Supply. Typically, the voltage is from 2.7V to 30V. A bypass capacitor of 0.1µF as close to the part as possible should be used between power supply pin and ground pin.

GND: Negative Power Supply.

Operation Overview

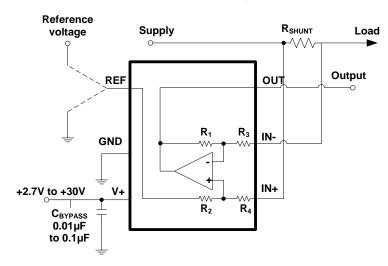
The TP182 family is 36V common-mode, zero-drift topology, current-sensing amplifiers that can be used in both low-side and high-side configurations. These specially-designed, current-sensing amplifiers are able to accurately measure voltages developed across current-sensing resistors on common-mode voltages that far exceed the supply voltage powering the device. Current can be measured on input voltage rails as high as 36 V while the device can be powered from supply voltages as low as 2.7 V.

The zero-drift topology enables high-precision measurements with maximum input offset voltages as low as $100\mu V$ with a maximum temperature contribution of $0.5~\mu V/^{\circ}C$ over the full temperature range of $-40^{\circ}C$ to $125^{\circ}C$.

Applications Information

Application schematic





Above figure shows the basic connections of the TP182. The input pins, IN+ and IN-, should be connected as closely as possible to the shunt resistor to minimize any resistance in series with the shunt resistor.

Power-supply bypass capacitors are required for stability. Applications with noisy or high-impedance power supplies may require additional decoupling capacitors to reject power-supply noise. Connect bypass capacitors close to the device pins.

Selecting RSHUNT

The zero-drift offset performance of the TP182 offers several benefits. Most often, the primary advantage of the low offset characteristic enables lower full-scale drops across the shunt. For example, nonzero-drift current shunt monitors typically require a full-scale range of 100 mV.

The TP182 family gives equivalent accuracy at a full-scale range on the order of 10 mV. This accuracy reduces shunt dissipation by an order of magnitude with many additional benefits.

Alternatively, there are applications that must measure current over a wide dynamic range that can take advantage of the low offset on the low end of the measurement. Most often, these applications can use the lower gains of the TP182 to accommodate larger shunt drops on the upper end of the scale. For instance, a TP182A1 operating on a 3.3-V supply could easily handle a full-scale shunt drop of 60 mV, with only 100uV of offset.

REF Input Impedance Effects

As with any difference amplifier, the TP182 family common-mode rejection ratio is affected by any impedance present at the REF input. This concern is not a problem when the REF pin is connected directly to most references or power supplies. When using resistive dividers from the power supply or a reference voltage, the REF pin should be buffered by an op amp.

Power Supply Recommendation

The input circuitry of the TP182 can accurately measure beyond its power-supply voltage, V+. For example, the V+ power supply can be 5 V, whereas the load power-supply voltage can be as high as 30 V. However, the output voltage range of the OUT pin is limited by the voltages on the power-supply pin. Note also that the TP182 can withstand the full input signal range up to 36 V at the input pins, regardless of whether the device has power applied or not.

Proper Board Layout

To ensure optimum performance at the PCB level, care must be taken in the design of the board layout. To avoid leakage currents, the surface of the board should be kept clean and free of moisture. Coating the surface creates a barrier to moisture accumulation and helps reduce parasitic resistance on the board.

Keeping supply traces short and properly bypassing the power supplies minimizes power supply disturbances due to output

www.3peak.com 8/ 13 Rev.A.5



current variation, such as when driving an ac signal into a heavy load. Bypass capacitors should be connected as closely as possible to the device supply pins. Stray capacitances are a concern at the outputs and the inputs of the amplifier. It is recommended that signal traces be kept at least 5mm from supply lines to minimize coupling.

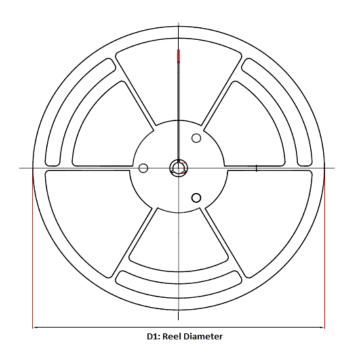
A variation in temperature across the PCB can cause a mismatch in the Seebeck voltages at solder joints and other points where dissimilar metals are in contact, resulting in thermal voltage errors. To minimize these thermocouple effects, orient resistors so heat sources warm both ends equally. Input signal paths should contain matching numbers and types of components, where possible to match the number and type of thermocouple junctions. For example, dummy components such as zero value resistors can be used to match real resistors in the opposite input path. Matching components should be located in close proximity and should be oriented in the same manner. Ensure leads are of equal length so that thermal conduction is in equilibrium. Keep heat sources on the PCB as far away from amplifier input circuitry as is practical.

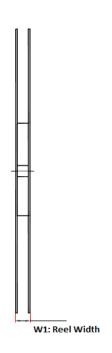
The use of a ground plane is highly recommended. A ground plane reduces EMI noise and also helps to maintain a constant temperature across the circuit board.

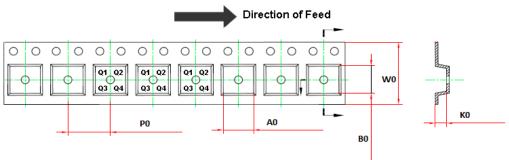
www.3peak.com 9/ 13 Rev.A.5



Tape and Reel Information







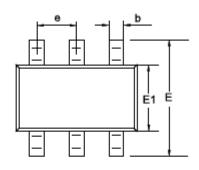
Order Number	Package	D1 (mm)	W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	W0 (mm)	Pin1 Quadrant
TP182xx-CR	SOT363(SC70-6)	178.0	12.1	2.4	2.5	1.2	4.0	8.0	Q3

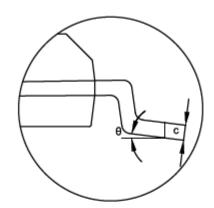
Package Outline Dimensions

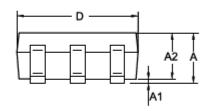
SC70-6 /SOT-363

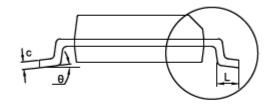
Package Outline Dimensions

SC6(SOT363-6-A)









Symbol		ensions imeters	Dimensions In Inches		
,	MIN	MAX	MIN	MAX	
Α	0.850	1,100	0.033	0.043	
A1	0.000	0.100	0.000	0.004	
A2	0.800	1.000	0.031	0.039	
b	0.150	0.350	0.006	0.014	
С	0.080	0.230	0.003	0.009	
D	2,000	2,200	0.079	0.087	
E	2.150	2.450	0.085	0.096	
E1	1.150	1.350	0.045	0.053	
е	0.65	0 BSC	0.02	26 BSC	
L	0.260	0.460	0.010	0.018	
θ	0	8°	0	8	

NOTES

- 1. Do not include mold flash or protrusion.
- 2. This drawing is subject to change without notice.



IMPORTANT NOTICE AND DISCLAIMER

Copyright© 3PEAK 2012-2023. All rights reserved.

Trademarks. Any of the 思瑞浦 or 3PEAK trade names, trademarks, graphic marks, and domain names contained in this document /material are the property of 3PEAK. You may NOT reproduce, modify, publish, transmit or distribute any Trademark without the prior written consent of 3PEAK.

Performance Information. Performance tests or performance range contained in this document/material are either results of design simulation or actual tests conducted under designated testing environment. Any variation in testing environment or simulation environment, including but not limited to testing method, testing process or testing temperature, may affect actual performance of the product.

Disclaimer. 3PEAK provides technical and reliability data (including data sheets), design resources (including reference designs), application or other design recommendations, networking tools, security information and other resources "As Is". 3PEAK makes no warranty as to the absence of defects, and makes no warranties of any kind, express or implied, including without limitation, implied warranties as to merchantability, fitness for a particular purpose or non-infringement of any third-party's intellectual property rights. Unless otherwise specified in writing, products supplied by 3PEAK are not designed to be used in any life-threatening scenarios, including critical medical applications, automotive safety-critical systems, aviation, aerospace, or any situations where failure could result in bodily harm, loss of life, or significant property damage. 3PEAK disclaims all liability for any such unauthorized use.

www.3peak.com 12/ 13 Rev.A.5



